5SDA 08D3205

Old part no. DA 807-780-32

Avalanche Diode

Properties

- low on-state voltage
- avalanche reverse characteristics
- high operational reliability
- suitable for parallel operation

Key Parameters

V_{RRM}	=	3 200	V
I_{FAVm}	=	910	A
I_{FSM}	=	9 200	A
V_{TO}	=	0.930	V
r_T	=	0.520	mΩ

Types

	V_{RRM}
5SDA 08D3205	**3 200 V**
Conditions:	*T_j = -40 ÷ 160 °C, half sine waveform, f = 50 Hz*

Mechanical Data

F_m	**Mounting force**	11 ± 1 kN
m	**Weight**	0.23 kg
D_S	**Surface creepage distan e**	30 mm
D_a	**Air strike distance**	20.5 mm

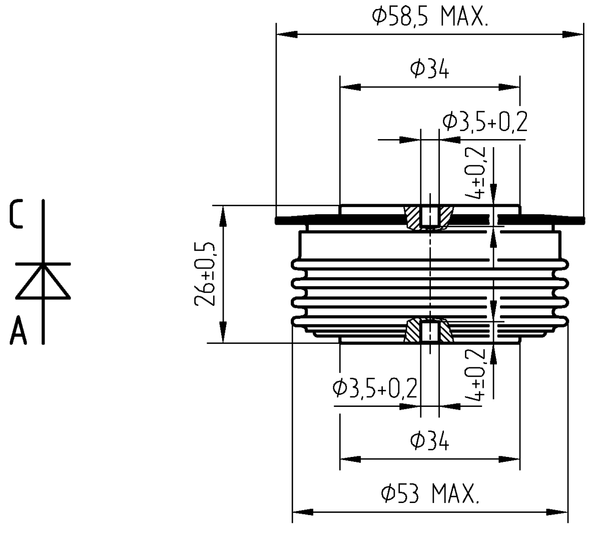

Fig. 1 Case

ABB s.r.o.
Novodvorska 1768/138a, 142 21 Praha 4, Czech Republic
tel.: +420 261 306 250, http://www.abb.com/semiconductors

Maximum Ratings			*Maximum Limits*	*Unit*
V_{RRM}	**Repetitive peak reverse voltage** *T_j = -40 ÷ 160 °C*		**3 200**	**V**
I_{FAVm}	**Average forward current** *T_c = 85 °C*		**910**	**A**
I_{FRMS}	**RMS forward current** *T_c = 85 °C*		**1 430**	**A**
I_{RRM}	**Repetitive reverse current** *$V_R = V_{RRM}$*		**50**	**mA**
I_{FSM}	**Non repetitive peak surge current** *V_R = 0 V, half sine pulse*	*t_p = 8.3 ms*	**9 800**	**A**
		t_p = 10 ms	**9 200**	**A**
I^2t	**Limiting load integral** *V_R = 0 V, half sine pulse*	*t_p = 8.3 ms*	**400 000**	**A^2s**
		t_p = 10 ms	**423 000**	**A^2s**
P_{RSM}	**Maximum avalanche power dissipation** *rectangular pulse 20 µs*		**50**	**kW**
T_{jmin} - T_{jmax}	**Operating temperature range**		**-40 ÷ 160**	**°C**
T_{STG}	**Storage temperature range**		**-40 ÷ 160**	**°C**

Unless otherwise specified T_j = 160 °C

Characteristics		*Value*			*Unit*
		min	*typ*	*max*	
V_{T0}	**Threshold voltage**			**0.930**	**V**
r_T	**Forward slope resistance** *I_F = 800 ÷ 2400 A*			**0.520**	**mΩ**
V_{FM}	**Maximum forward voltage** *I_{FM} = 1 800 A*			**1.910**	**V**
Q_{rr}	**Recovered charge** *V_R = 100 V, I_{FM} = 1 000 A, di_F/dt = -5 A/µs*		**1 050**		**µC**

Unless otherwise specified T_j = 160 °C

Thermal Parameters			*Value*	*Unit*
R_{thjc}	**Thermal resistance junction to case**	*double side cooling*	**40**	**K/kW**
		anode side cooling	**65**	
		cathode side cooling	**104**	
R_{thch}	**Thermal resistance case to heatsink**	*double side cooling*	**10**	**K/kW**
		single side cooling	**20**	

Transient Thermal Impedance

Analytical function for transient thermal impedance

$$Z_{thjc} = \sum_{i=1}^{4} R_i (1 - \exp(-t / \tau_i))$$

Conditions:

F_m = 11 ± 1 kN, Double side cooled

i	1	2	3	4
R_i(K/kW)	20.95	10.57	7.15	1.33
τ_i (s)	0.396	0.072	0.009	0.0044

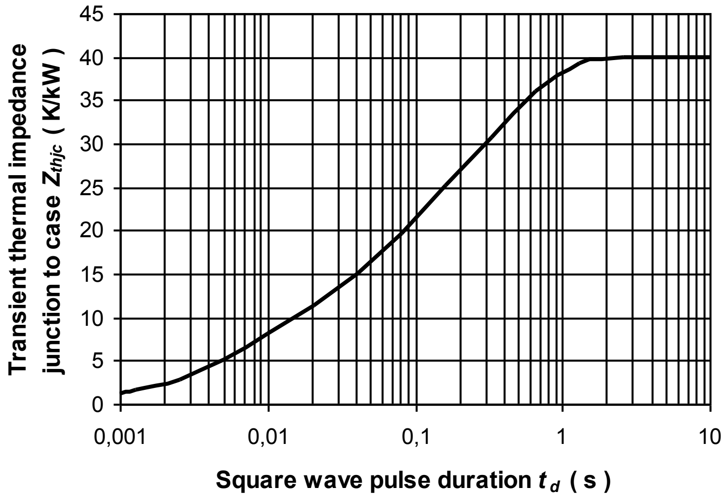

Fig. 2 Transient thermal impedance junction to case

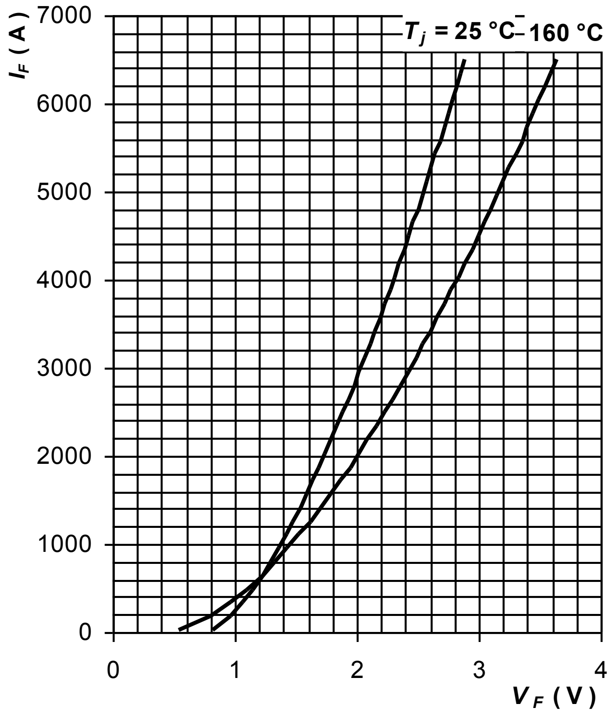

Fig. 3 Maximum forward voltage drop characteristics

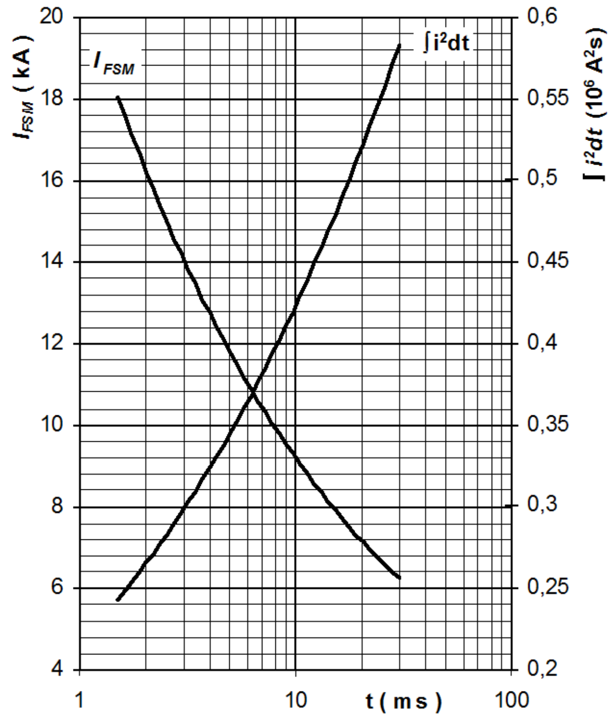

Fig. 4 Surge forward current vs. pulse length, half sine wave, single pulse, V_R = 0 V, $T_j = T_{jmax}$

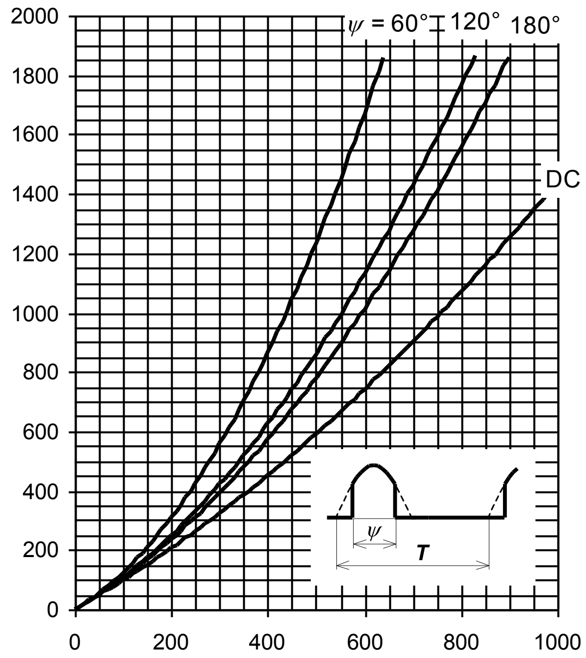

Fig. 5 Forward power loss vs. average forward current, sine waveform, f = 50 Hz, T = 1/f

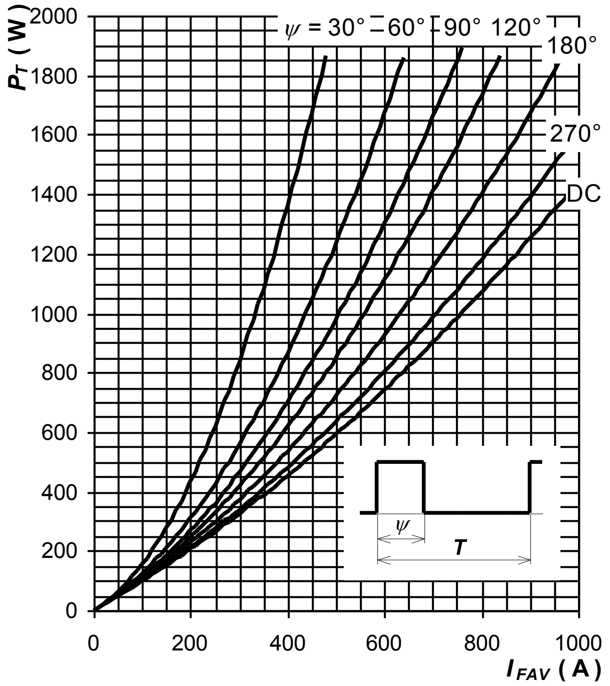

Fig. 6 Forward power loss vs. average forward current, square waveform, f = 50 Hz, T = 1/f

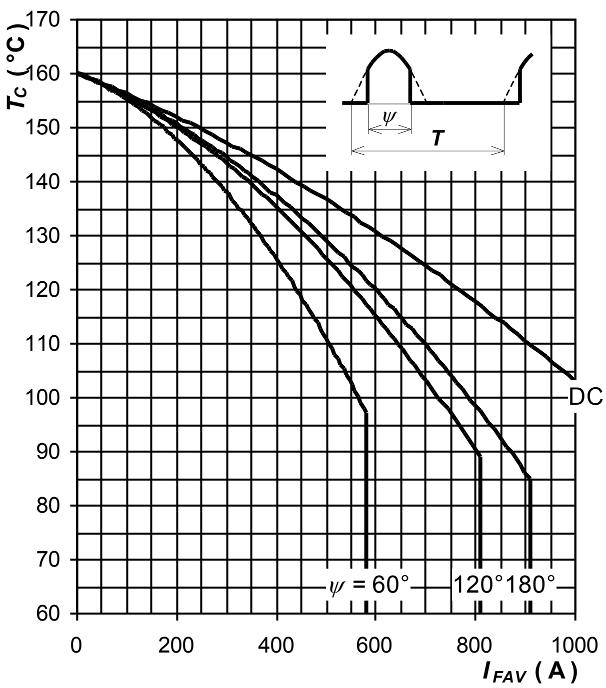

Fig. 7 Max. case temperature vs. aver. forward current, sine waveform, f = 50 Hz, T = 1/f

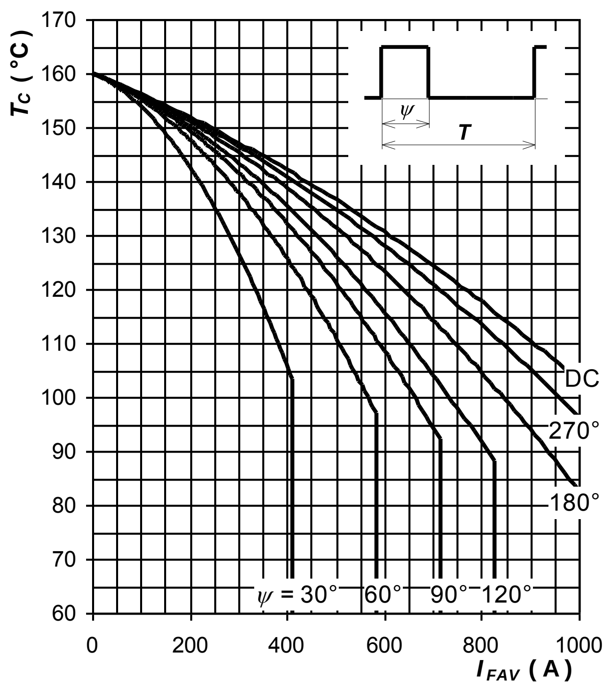

Fig. 8 Max.case temperature vs. aver. forward current, square waveform, f = 50 Hz, T = 1/f

Notes: